



AF/2811

Docket No.: 57454-162

Corres. and Mail  
**BOX AF**PATENT**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Application of

: **RESPONSE UNDER 37 CFR 1.116**

Yukio MAKI

: **EXPEDITED PROCEDURE**

Serial No.: 09/909,975

: Group Art Unit: 2811

Filed: July 23, 2001

: Examiner: S. Gebremariam

For: SEMICONDUCTOR DEVICE AND MANUFACTURING METHOD OF THE SAME

*#12/Amendt A...*  
*3/18/03*  
*Enter...*  
*4/22/03*

**AMENDMENT UNDER 37 CFR §1.116**Box AF  
Commissioner for Patents  
Washington, DC 20231

Sir:

The following Amendment and Remarks are submitted in response to the Office Action dated December 12, 2002, pursuant to the provisions of 37 C.F.R. §1.116.

RECEIVED  
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TECHNOLOGY CENTER 2800**IN THE CLAIMS:**

Please amend claim 1 as follows.

1. (Amended) A semiconductor device, comprising:

a semiconductor substrate including an active region and an isolation region; and

a gate electrode formed on said active region with an insulating film interposed

therebetween, wherein:

a surface of said active region is entirely rounded so as to be inclined downward toward said isolation region;

said semiconductor device includes an SRAM (Static Random Access Memory);